L Number	Hits	Search Text	DB	Time stamp
-	603	(345/82-83).CCLS.	USPAT; EPO; JPO; IBM_TDB	2002/07/18 14:34
-	824	(345/76-81).CCLS.	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:28
-	11911	(current or voltage) near5 color	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:40
-	73	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and ((current or voltage) near5 color)	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:39
-	2	("3740570").PN.	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:32
-	25994	(TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:22
-	113	((TFT or (thin adj film adj transistor))) same ((current or voltage) near5 color)	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:41
-	1	(((345/82-83).CCLS.) or ((345/76-81).CCLS.)) and (((TFT or (thin adj film adj transistor))) same ((current or voltage) near5 color))	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:39
-	6107	((current or voltage near2 control)) near5 color	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:46
-	20	((TFT or (thin adj film adj transistor))) same (((current or voltage near2 control)) near5 color)	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:48
-	715	((current or voltage) near2 control) near5 color	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:48
-	4	((TFT or (thin adj film adj transistor))) same (((current or voltage) near2 control) near5 color)	USPAT; EPO; JPO; IBM_TDB	2002/07/15 14:48
-	2	jp-10039791-$.did.	EPO; JPO; DERWENT	2002/07/17 10:45
-	1	1998-184157.NRAN.	DERWENT	2002/07/17 10:46
-	896	(TFT or (thin adj film adj transistor)) near5 size	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:33
-	16	("W/L" or "W adj L") same ((TFT or (thin adj film adj transistor)) near5 size)	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:33
-	2	JP-09236790-$.did.	EPO; JPO; DERWENT	2002/07/17 13:29
-	12497	("W/L" or ("W" adj "L"))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:34
-	127	(TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L")))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:33
-	16	("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor)) near5 size)	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:34
-	0	(("W/L" or ("W" adj "L")) same ((TFT or (thin adj film adj transistor)) near5 size)) not (("W/L" or "W adj L") same ((TFT or (thin adj film adj transistor)) near5 size))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:34
-	2	((TFT or (thin adj film adj transistor)) same (("W/L" or ("W" adj "L")))) same color	USPAT; EPO; JPO; IBM_TDB	2002/07/17 13:35

-	1	("4810060").PN.	USPAT; EPO; JPO; IBM_TDB	2002/07/17 14:25
-	6	("4600274" | "4601546" | "4716403" | "4728172" | "4728175" | "4761058").PN.	USPAT	2002/07/17 14:25
-	15	4810060.URPN.	USPAT	2002/07/17 14:26
-	2	(TFT or (thin adj film adj transistor)) same (emission adj efficiency)	USPAT; EPO; JPO; IBM_TDB	2002/07/18 09:24
-	537	(TFT or (thin adj film adj transistor)) same (electroluminescence or "EL")	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:27
-	129	(TFT or (thin adj film adj transistor)) same (electroluminescence)	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:27
-	20	(TFT or (thin adj film adj transistor)) same (electroluminescence adj element)	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:35
-	3250	switching near3 (TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:37
-	2161	driving near3 (TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:38
-	230	(switching near3 (TFT or (thin adj film adj transistor))) same (driving near3 (TFT or (thin adj film adj transistor)))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:37
-	171	(switching near3 (TFT or (thin adj film adj transistor))) with (driving near3 (TFT or (thin adj film adj transistor)))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:37
-	401	switching adj (TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:38
-	478	driving adj (TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:38
-	17	(switching adj (TFT or (thin adj film adj transistor))) same (driving adj (TFT or (thin adj film adj transistor)))	USPAT; EPO; JPO; IBM_TDB	2002/07/17 15:38
-	26028	(TFT or (thin adj film adj transistor))	USPAT; EPO; JPO; IBM_TDB	2002/07/18 09:23
-	62	((TFT or (thin adj film adj transistor))) and (emission adj efficiency)	USPAT; EPO; JPO; IBM_TDB	2002/07/18 09:24
-	214	((TFT or (thin adj film adj transistor))) and (chromaticity)	USPAT; EPO; JPO; IBM_TDB	2002/07/18 09:25
-	3	(((TFT or (thin adj film adj transistor))) and (emission adj efficiency)) and (((TFT or (thin adj film adj transistor))) and (chromaticity))	USPAT; EPO; JPO; IBM_TDB	2002/07/18 09:25
-	2	("5550066" | "5684365").PN.	USPAT	2002/07/18 09:29
-	2	("6204610").PN.	USPAT; DERWENT	2002/07/18 10:24
-	1	2000-651206.NRAN.	DERWENT	2002/07/18 10:25
-	1	("5684365").PN.	USPAT; EPO; JPO; IBM_TDB	2002/07/18 10:57
-	1	("6072272").PN.	USPAT; EPO; JPO; IBM_TDB	2002/07/18 12:02
-	8	("4193015" | "4220892" | "5045750" | "5311337" | "5317437" | "5467422" | "5565754" | "5654729").PN.	USPAT	2002/07/18 11:49
-	0	6072272.URPN.	USPAT	2002/07/18 11:50

-	2	("6366025").PN.		USPAT; EPO; JPO; DERWENT	2002/07/18 12:02
-	1	2001-082367.NRAN.		DERWENT	2002/07/18 12:02
-	1	2001-082367.NRAN.		DERWENT	2002/07/18 12:04
-	1	2001-082367.NRAN.		DERWENT	2002/07/18 12:05
-	1	("6072272").PN.		USPAT; EPO; JPO; IBM_TDB	2002/07/18 15:04
-	1	("6121726").PN.		USPAT; EPO; JPO; IBM_TDB	2002/07/18 15:04